

## The RF Sub-Micron Bipolar Line RF Power Bipolar Transistor

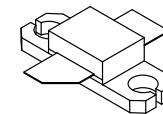
Designed for broadband commercial and industrial applications at frequencies from 1800 to 2000 MHz. The high gain and broadband performance of this device makes it ideal for large-signal, common-emitter class A and class AB amplifier applications. Suitable for frequency modulated, amplitude modulated and multi-carrier base station RF power amplifiers.

- Specified 26 Volts, 2.0 GHz, Class AB, Two-Tones Characteristics
  - Output Power — 30 Watts (PEP)
  - Power Gain — 9.8 dB
  - Efficiency — 34%
  - Intermodulation Distortion — -28 dBc
- Typical 26 Volts, 1.88 GHz, Class AB, CW Characteristics
  - Output Power — 30 Watts
  - Power Gain — 10.5 dB
  - Efficiency — 40%
- Excellent Thermal Stability
- Capable of Handling 3:1 VSWR @ 26 Vdc, 2000 MHz, 30 Watts (PEP) Output Power
- Characterized with Series Equivalent Large-Signal Impedance Parameters
- S-Parameter Characterization at High Bias Levels
- Designed for FM, TDMA, CDMA, and Multi-Carrier Applications

**MRF20030**

30 W, 2.0 GHz  
NPN SILICON  
BROADBAND

RF POWER TRANSISTOR



CASE 395D-03, STYLE 1

### MAXIMUM RATINGS

| Rating  | Symbol           | Value        | Unit          |
|---|------------------|--------------|---------------|
| Collector-Emitter Voltage   | V <sub>CEO</sub> | 25           | Vdc           |
| Collector-Emitter Voltage   | V <sub>CES</sub> | 60           | Vdc           |
| Collector-Base Voltage  | V <sub>CBO</sub> | 60           | Vdc           |
| Collector-Emitter Voltage (R <sub>BE</sub> = 100 Ω)                   | V <sub>CER</sub> | 30           | Vdc           |
| Emitter-Base Voltage  | V <sub>EB</sub>  | -3           | Vdc           |
| Collector Current – Continuous  | I <sub>C</sub>   | 4            | Adc           |
| Total Device Dissipation @ T <sub>C</sub> = 25°C<br>Derate above 25°C | P <sub>D</sub>   | 125<br>0.71  | Watts<br>W/°C |
| Storage Temperature Range   | T <sub>stg</sub> | - 65 to +150 | °C            |
| Operating Junction Temperature  | T <sub>J</sub>   | 200          | °C            |

### THERMAL CHARACTERISTICS

| Rating                                   | Symbol           | Max | Unit |
|--|------------------|-----|------|
| Thermal Resistance, Junction to Case (1) | R <sub>θJC</sub> | 1.4 | °C/W |

(1) Thermal resistance is determined under specified RF operating condition.

### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|                |        |     |     |     |      |

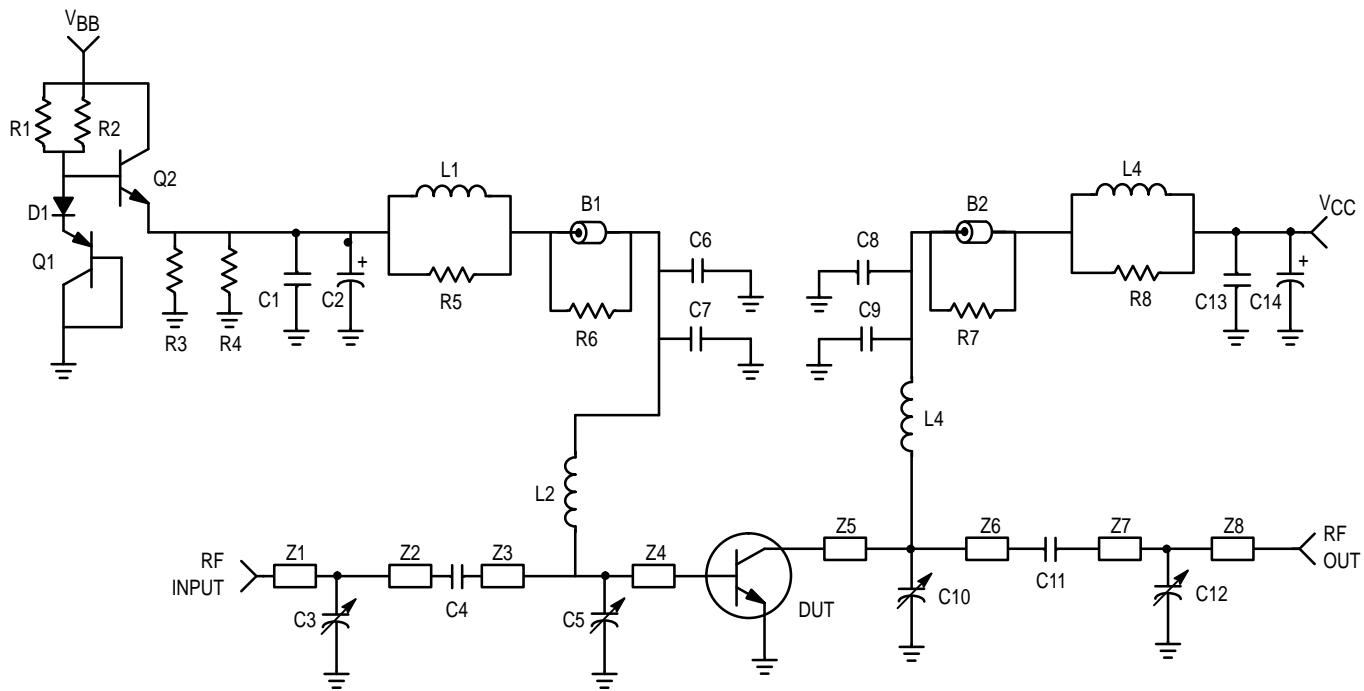
### OFF CHARACTERISTICS

|  |                      |    |    |   |     |
|--|----------------------|----|----|---|-----|
| Collector-Emitter Breakdown Voltage<br>(I <sub>C</sub> = 25 mAdc, I <sub>B</sub> = 0)  | V <sub>(BR)CEO</sub> | 25 | 26 | — | Vdc |
| Collector-Emitter Breakdown Voltage<br>(I <sub>C</sub> = 25 mAdc, V <sub>BE</sub> = 0) | V <sub>(BR)CES</sub> | 60 | 70 | — | Vdc |
| Collector-Base Breakdown Voltage<br>(I <sub>C</sub> = 25 mAdc, I <sub>E</sub> = 0)     | V <sub>(BR)CBO</sub> | 60 | 70 | — | Vdc |

**ELECTRICAL CHARACTERISTICS — continued** ( $T_C = 25^\circ\text{C}$  unless otherwise noted)

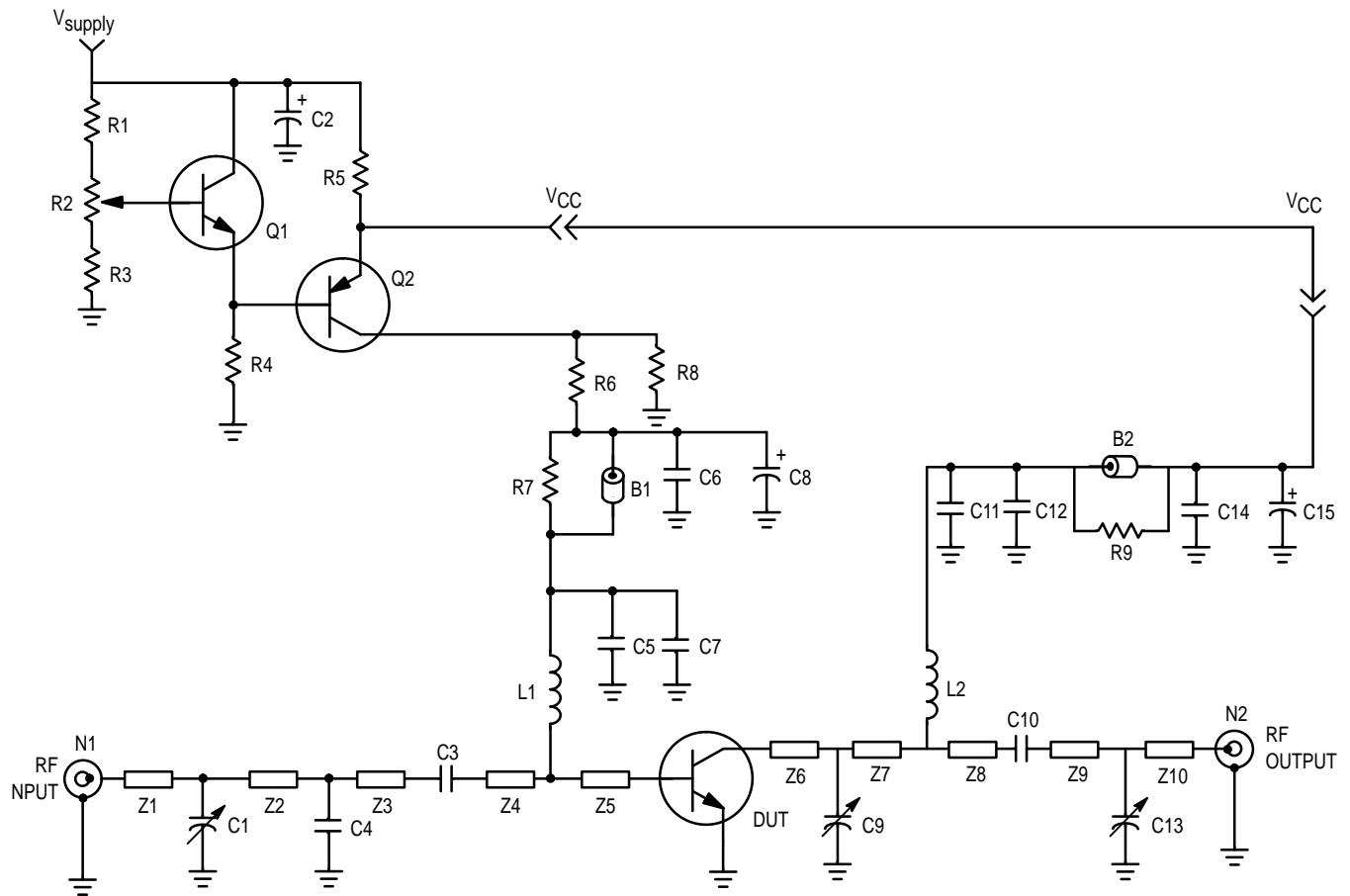
| Characteristic   | Symbol                      | Min                                      | Typ  | Max | Unit  |
|--|-----------------------------|--|------|-----|-------|
| <b>OFF CHARACTERISTICS</b>   |                             |  |      |     |       |
| Emitter–Base Breakdown Voltage<br>( $I_B = 5 \text{ mA DC}$ , $I_C = 0$ )  | $V_{(\text{BR})\text{EBO}}$ | 3  | 3.8  | —   | Vdc   |
| Collector Cutoff Current<br>( $V_{CE} = 30 \text{ Vdc}$ , $V_{BE} = 0$ )   | $I_{CES}$                   | —  | —    | 10  | mA DC |
| <b>ON CHARACTERISTICS</b>  |                             |  |      |     |       |
| DC Current Gain<br>( $V_{CE} = 5 \text{ Vdc}$ , $I_{CE} = 1 \text{ Adc}$ )   | $\text{h}_{FE}$             | 20                                       | 40   | 80  | —     |
| <b>DYNAMIC CHARACTERISTICS</b>   |                             |  |      |     |       |
| Output Capacitance<br>( $V_{CB} = 26 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ ) (1)  | $C_{ob}$                    | —  | 28   | —   | pF    |
| <b>FUNCTIONAL TESTS</b> (In Motorola Test Fixture)   |                             |  |      |     |       |
| Common–Emitter Amplifier Power Gain<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts}$ , $I_{CQ} = 120 \text{ mA}$ ,<br>$f_1 = 2000.0 \text{ MHz}$ , $f_2 = 2000.1 \text{ MHz}$ )   | $G_{pe}$                    | 9.8                                      | 10.5 | —   | dB    |
| Collector Efficiency<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts (PEP)}$ , $I_{CQ} = 120 \text{ mA}$ ,<br>$f_1 = 2000.0 \text{ MHz}$ , $f_2 = 2000.1 \text{ MHz}$ )  | $\eta$                      | 34                                       | 38   | —   | %     |
| Intermodulation Distortion<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts (PEP)}$ , $I_{CQ} = 120 \text{ mA}$ ,<br>$f_1 = 2000.0 \text{ MHz}$ , $f_2 = 2000.1 \text{ MHz}$ )  | IMD                         | —  | −33  | −28 | dBc   |
| Input Return Loss<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts (PEP)}$ , $I_{CQ} = 125 \text{ mA}$ ,<br>$f_1 = 2000.0 \text{ MHz}$ , $f_2 = 2000.1 \text{ MHz}$ )   | IRL                         | 10                                       | 17   | —   | dB    |
| Load Mismatch<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts (PEP)}$ , $I_{CQ} = 120 \text{ mA}$ ,<br>$f_1 = 2000.0 \text{ MHz}$ , $f_2 = 2000.1 \text{ MHz}$ , Load VSWR = 3:1, All Phase Angles at Frequency of Test) | $\Psi$                      | No Degradation in Output Power           |      |     |       |
| Common–Emitter Amplifier Power Gain<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts (PEP)}$ , $I_{CQ} = 125 \text{ mA}$ ,<br>$f_1 = 1930.0 \text{ MHz}$ , $f_2 = 1930.1 \text{ MHz}$ )                                   | $G_{pe}$                    | —  | 10.5 | —   | dB    |
| Collector Efficiency<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts (PEP)}$ , $I_{CQ} = 125 \text{ mA}$ ,<br>$f_1 = 1930.0 \text{ MHz}$ , $f_2 = 1930.1 \text{ MHz}$ )  | $\eta$                      | —  | 34   | —   | %     |
| Intermodulation Distortion<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts (PEP)}$ , $I_{CQ} = 125 \text{ mA}$ ,<br>$f_1 = 1930.0 \text{ MHz}$ , $f_2 = 1930.1 \text{ MHz}$ )  | IMD                         | —  | −35  | —   | dBc   |
| Input Return Loss<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts (PEP)}$ , $I_{CQ} = 125 \text{ mA}$ ,<br>$f_1 = 1930.0 \text{ MHz}$ , $f_2 = 1930.1 \text{ MHz}$ )   | IRL                         | —  | 14   | —   | dB    |
| <b>GUARANTEED BUT NOT TESTED</b> (In Motorola Test Fixture)  |                             |  |      |     |       |
| Common–Emitter Amplifier Power Gain<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts}$ , $I_{CQ} = 125 \text{ mA}$ , $f = 1880 \text{ MHz}$ )   | $G_{pe}$                    | —  | 10.5 | —   | dB    |
| Collector Efficiency<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts}$ , $I_{CQ} = 125 \text{ mA}$ , $f = 1880 \text{ MHz}$ )  | $\eta$                      | —  | 40   | —   | %     |
| Input Return Loss<br>( $V_{CC} = 26 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts}$ , $I_{CQ} = 125 \text{ mA}$ , $f = 1880 \text{ MHz}$ )   | IRL                         | —  | 14   | —   | dB    |
| Output Mismatch Stress<br>( $V_{CC} = 25 \text{ Vdc}$ , $P_{out} = 30 \text{ Watts}$ , $I_{CQ} = 125 \text{ mA}$ ,<br>$f = 1880 \text{ MHz}$ , VSWR = 3:1, All Phase Angles at Frequency of Test)                                    | $\Psi$                      | Typically No Degradation in Output Power |      |     |       |

(1) For Information Only. This Part Is Collector Matched.



|             |  |        |   |
|-------------|--|--------|---|
| B1, B2      | Ferrite Bead, P/N 5659065/3B, Ferroxcube           | N1, N2 | Type N Flange Mount RF Connector<br>MA/COM 3052-1648-10           |
| C1, C13     | 0.1 $\mu$ F, Chip Capacitor, Kermet                | R1, R2 | 130 $\Omega$ , 1/8 W Chip Resistor, Rohm                          |
| C2          | 100 $\mu$ F, 50 V, Electrolytic Capacitor, Mallory | R3, R4 | 100 $\Omega$ , 1/8 W Chip Resistor, Rohm                          |
| C3, C5, C12 | 0.6–4 pF, Variable Capacitor, Johanson, Gigatrim   | R5, R8 | 10 $\Omega$ , 1/2 W Resistor                                      |
| C4, C11     | 10 pF, B Case Chip Capacitor, ATC                  | R6, R7 | 10 $\Omega$ , 1/8 W Chip Resistor, Rohm (10J)                     |
| C6, C8      | 24 pF, B Case Chip Capacitor, ATC                  | Q1     | Transistor, PNP Motorola (BD136)                                  |
| C7, C9      | 75 pF, B Case Chip Capacitor, ATC                  | Q2     | Transistor, NPN Motorola (MJD47)                                  |
| C10         | 0.4–2.5 pF, Variable Capacitor, Johanson, Gigatrim | Board  | 30 Mil Glass Teflon®, Arlon GX-0300-55-22,<br>$\epsilon_r = 2.55$ |
| C14         | 470 $\mu$ F, 63 V, Electrolytic Capacitor, Mallory |        |   |
| D1          | Diode, Motorola (MUR3160T3)                        |        |   |
| L1, L4      | 12 Turns, 22 AWG, IDIA. 0.195"                     |        |   |
| L2, L3      | 0.750" 20 AWG                                      |        |   |

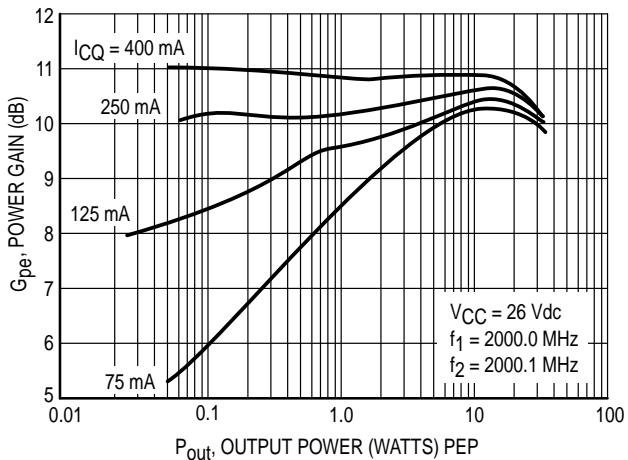
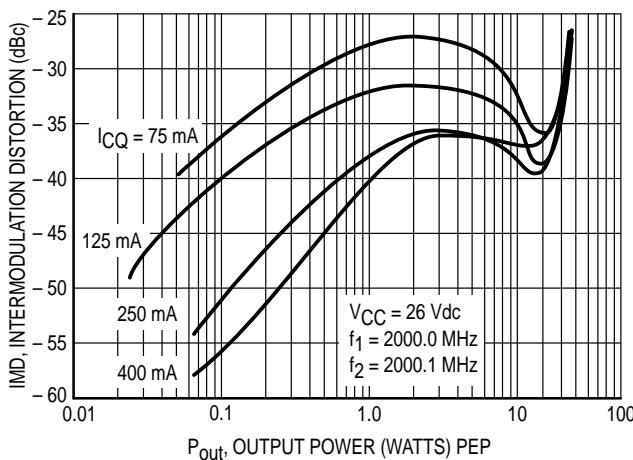
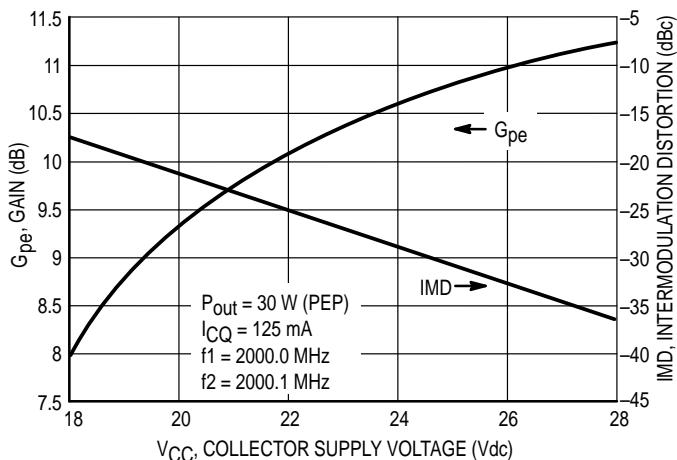
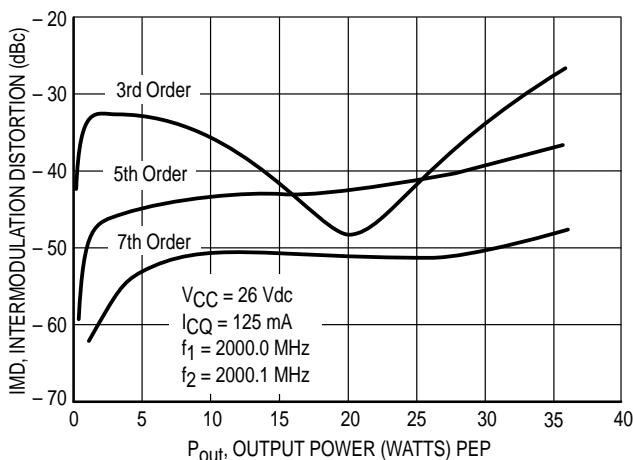
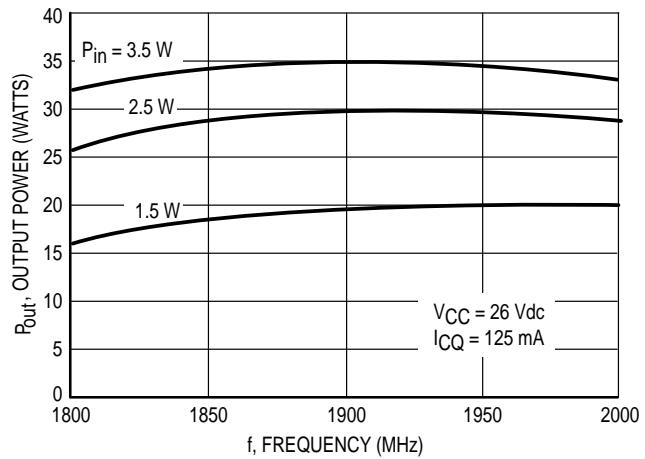
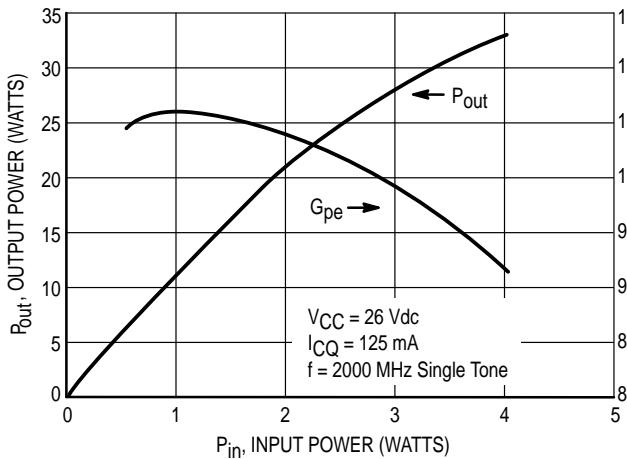
Figure 1. Class AB Test Fixture Electrical Schematic



|             |  |        |  |
|-------------|--|--------|--|
| B1, B2      | Long Bead, Fair Rite                             | Q1     | Transistor, NPN, Motorola (BD135)                              |
| C1, C9, C13 | 0.6–4 pF, Variable Capacitor, Johanson, Gigatrim | Q2     | Transistor, PNP, Motorola (BD136)                              |
| C2, C8      | 100 µF, 50 V, Electrolytic Capacitor, Mallory    | R1     | 250 Ω, Chip Resistor, 1/8 Watt, Rohm                           |
| C3, C10     | 18 pF B Case Chip Capacitor, ATC                 | R2     | 500 Ω, 1/4 Watt, Potentiometer                                 |
| C4          | 1.3 pF, B Case Chip Capacitor, ATC               | R3     | 4.7 kΩ, Chip Resistor, 1/8 Watt, Rohm                          |
| C5, C11     | 24 pF, B Case Chip Capacitor, ATC                | R4     | 2 x 4.7 kΩ, Chip Resistor, 1/8 Watt, Rohm                      |
| C6, C14     | 0.1 µF, Chip Capacitor, Kermet                   | R5     | 1.0 Ω, 10 Watt, Resistor, DALE                                 |
| C7, C12     | 75 pF, B Case Chip Capacitor, ATC                | R6     | 39 Ω, 1 Watt, Resistor   |
| C15         | 470 µF, 63 V, Electrolytic Capacitor, Mallory    | R7, R9 | 4 x 39 Ω, Chip Resistors, 1/8 Watt, Rohm                       |
| L1, L2      | 0.75 in., 20 AWG                                 | R8     | 75 Ω, Chip Resistor, 1/8 Watt, Rohm                            |
| N1, N2      | Type N Flange Mount RF Connector, MA/COM         | Board  | 30 Mil Glass Teflon®, Arlon GX-0300-55-22, $\epsilon_r = 2.55$ |

Figure 2. Class A Test Fixture Electrical Schematic

## TYPICAL CHARACTERISTICS



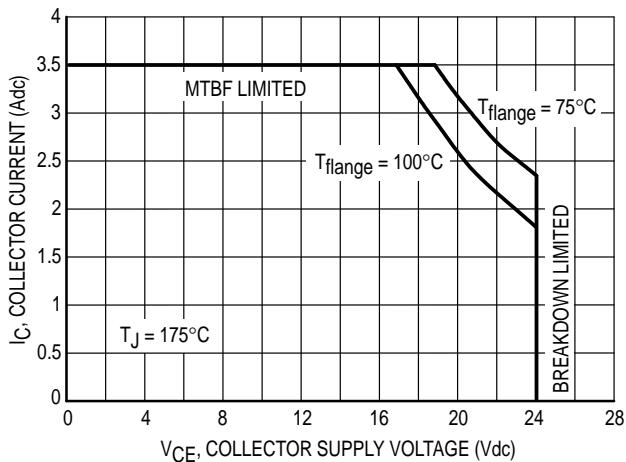


Figure 9. DC Class A Safe Operating Area

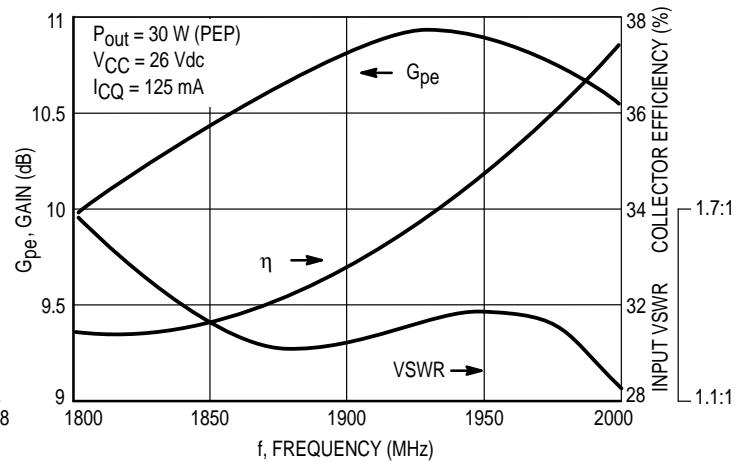


Figure 10. Performance in Broadband Circuit

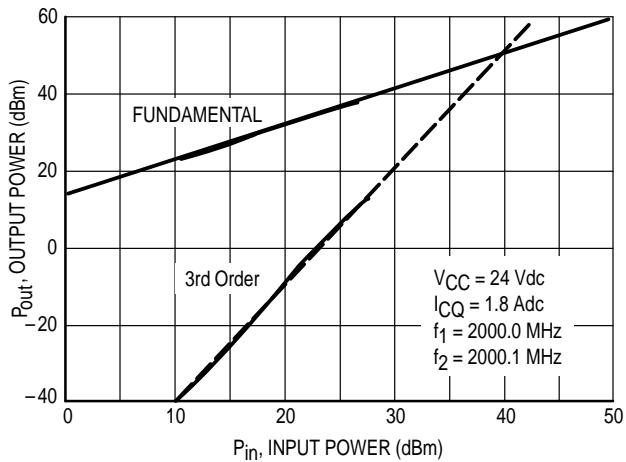
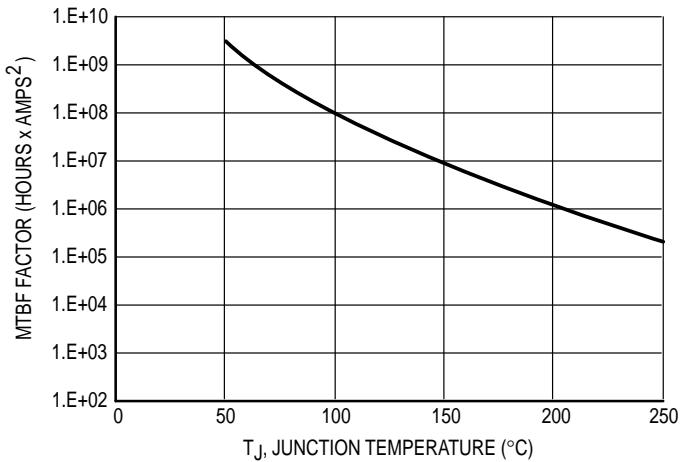
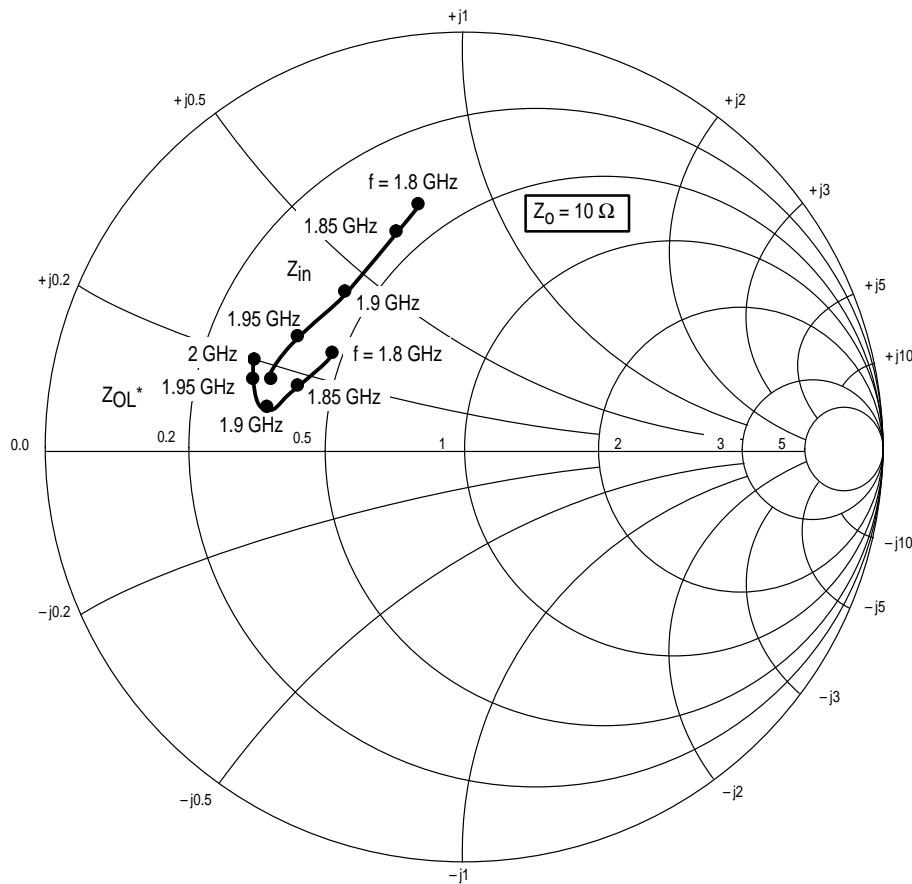


Figure 11. Class A Third Order Intercept Point



This above graph displays calculated MTBF in hours  $\times$  ampere $^2$  emitter current. Life tests at elevated temperatures have correlated to better than  $\pm 10\%$  of the theoretical prediction for metal failure. Divide MTBF factor by  $I_C^2$  for MTBF in a particular application.

Figure 12. MTBF Factor versus Junction Temperature



$V_{CC} = 26 \text{ V}$ ,  $I_{CQ} = 125 \text{ mA}$ ,  $P_{out} = 30 \text{ W (PEP)}$

| $f$<br>MHz | $Z_{in}(1)$<br>$\Omega$ | $Z_{OL^*}$<br>$\Omega$ |
|------------|-------------------------|------------------------|
| 1800       | $4.5 + j7.0$            | $4.7 + j2.4$           |
| 1850       | $4.5 + j6.0$            | $4.4 + j1.6$           |
| 1900       | $4.5 + j4.6$            | $3.4 + j1.2$           |
| 1950       | $3.7 + j2.4$            | $3.3 + j1.6$           |
| 2000       | $3.5 + j1.5$            | $3.5 + j2.0$           |

$Z_{in}(1)$  = Conjugate of fixture base impedance.

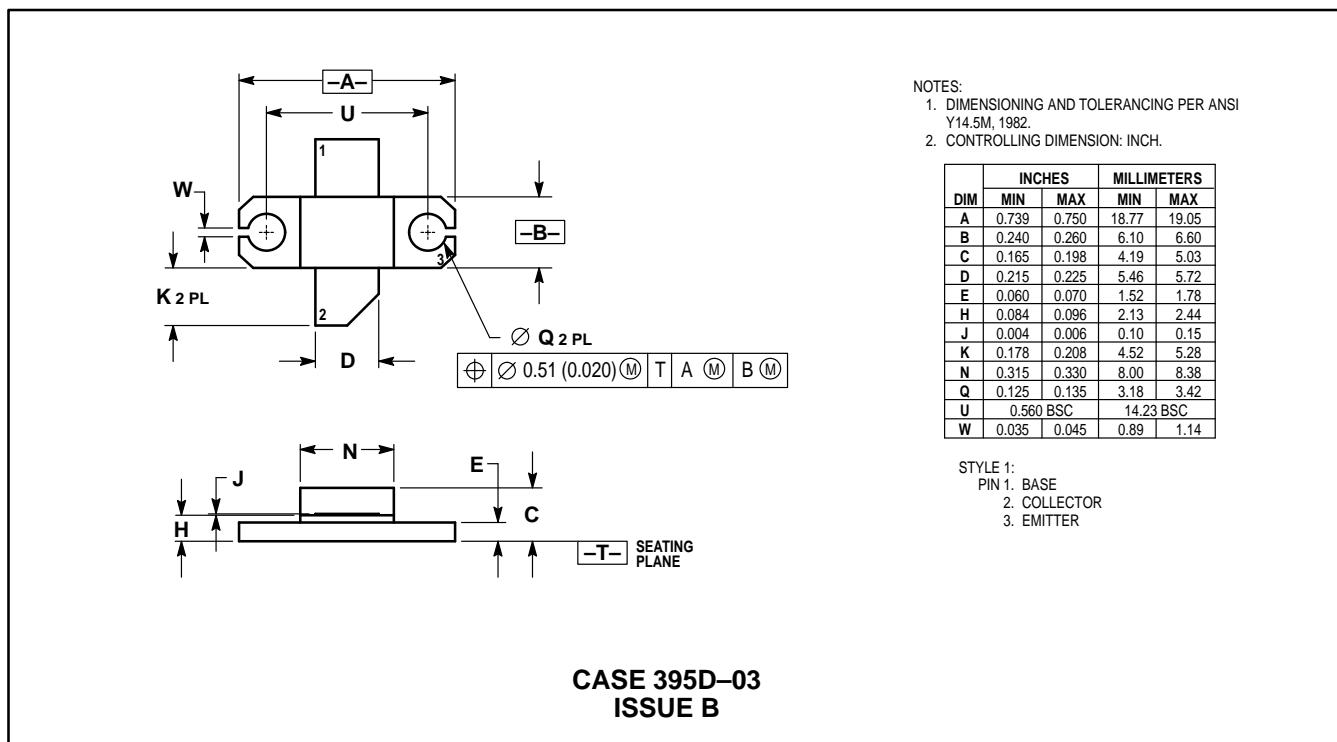
$Z_{OL^*}$  = Conjugate of the optimum load impedance at given output power, voltage, bias current and frequency.

**Figure 13. Series Equivalent Input and Output Impedance**

**Table 1. Common Emitter S–Parameters at  $V_{CE} = 24$  Vdc,  $I_C = 1.8$  Adc**

| f<br>GHz | <b>S<sub>11</sub></b> |     | <b>S<sub>21</sub></b> |      | <b>S<sub>12</sub></b> |     | <b>S<sub>22</sub></b> |     |
|----------|-----------------------|-----|-----------------------|------|-----------------------|-----|-----------------------|-----|
|          | S <sub>11</sub>       | ∠φ  | S <sub>21</sub>       | ∠φ   | S <sub>12</sub>       | ∠φ  | S <sub>22</sub>       | ∠φ  |
| 1.5      | .964                  | 158 | .65                   | 74   | .046                  | 60  | .859                  | 161 |
| 1.55     | .960                  | 156 | .74                   | 68   | .047                  | 56  | .841                  | 161 |
| 1.6      | .952                  | 155 | .87                   | 60   | .049                  | 53  | .815                  | 160 |
| 1.65     | .933                  | 153 | 1.05                  | 50   | .048                  | 46  | .787                  | 161 |
| 1.7      | .892                  | 149 | 1.32                  | 35   | .047                  | 40  | .744                  | 163 |
| 1.75     | .804                  | 149 | 1.64                  | 13   | .040                  | 29  | .719                  | 168 |
| 1.8      | .727                  | 157 | 1.78                  | -18  | .026                  | 21  | .778                  | 175 |
| 1.85     | .787                  | 163 | 1.50                  | -50  | .015                  | 54  | .883                  | 174 |
| 1.9      | .873                  | 163 | 1.14                  | -73  | .020                  | 81  | .937                  | 171 |
| 1.95     | .921                  | 160 | .84                   | -89  | .026                  | 88  | .949                  | 168 |
| 2        | .941                  | 157 | .62                   | -102 | .031                  | 93  | .950                  | 165 |
| 2.05     | .943                  | 155 | .48                   | -109 | .036                  | 93  | .946                  | 164 |
| 2.1      | .940                  | 153 | .38                   | -118 | .040                  | 92  | .942                  | 163 |
| 2.15     | .928                  | 151 | .30                   | -127 | .042                  | 97  | .939                  | 162 |
| 2.2      | .917                  | 150 | .24                   | -133 | .049                  | 99  | .935                  | 161 |
| 2.25     | .907                  | 150 | .20                   | -140 | .056                  | 101 | .933                  | 160 |
| 2.3      | .888                  | 148 | .17                   | -150 | .066                  | 100 | .926                  | 159 |
| 2.35     | .861                  | 148 | .14                   | -159 | .077                  | 98  | .916                  | 157 |
| 2.4      | .853                  | 149 | .11                   | -167 | .087                  | 92  | .909                  | 157 |
| 2.45     | .860                  | 146 | .10                   | -176 | .095                  | 89  | .900                  | 155 |
| 2.5      | .880                  | 146 | .10                   | 156  | .119                  | 84  | .880                  | 155 |

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